mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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High Power Infrared LED

Product No: MTE8560P-C

Peak Emission Wavelength: 850nm

The 850nm high power infrared LED Series is designed for application requiring high accuracy and precision as well as uniform spectral emission. Custom package solutions and sorting are available.

FEATURES

- > Hermetically Sealed TO-18
- > High Output Power
- > Gold Plated Dome Lens
- > Narrow Beam Angle / High Reliability
- APPLICATIONS
- > Optical Scanning
- > Linear & Rotary Encoder> Edge Sensing / Optical Sensors
- > Optical Switches / Security Systems



Absolute Maximum Ratings (Ta=25°C)

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TEMS	SYMBOL	RATINGS	UNIT	lead-free
Forward Current (DC)	IF	100	mA	
Forward Current (Pulse)*1	IFP	1	A	
Reverse Voltage	VR	5	V	
Power Dissipation	PD	200	mW	
Operating Temperature Range	Topr	-20 ~ +85	Oo	
Storage Temperature Range	Tstg	-30 ~ +100	℃	
Junction Temperature	Тј	260	Oo	

*1: Tw=10µsec, T=10msec.

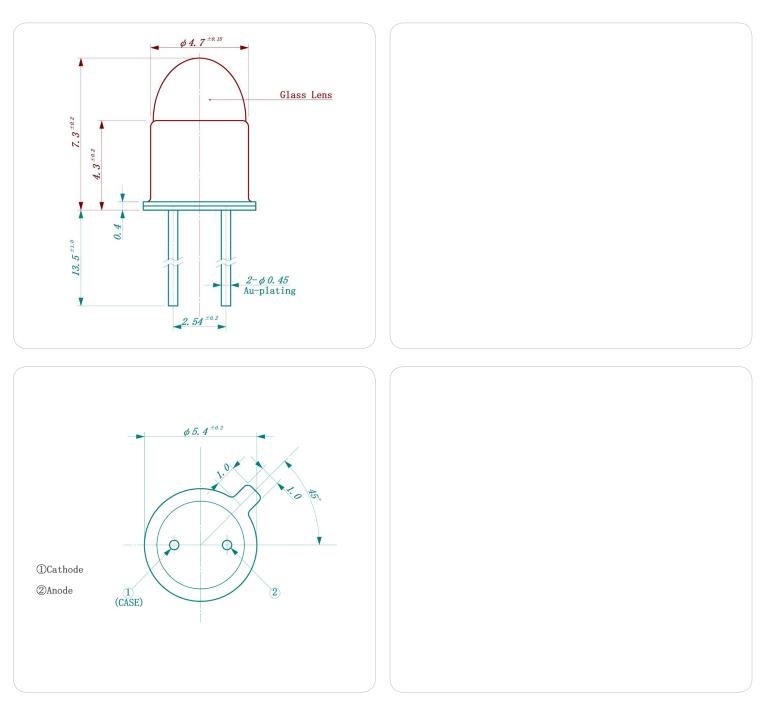
Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNIT
Power Output	PO	IF=50mA		6.0		mW
Forward Voltage	VF	IF=50mA		1.5	2.0	V
Reverse Current	IR	VR=5V			10	μA
Peak Emission Wavelength	λρ	IF=50mA		850		nm
Spectral Line Half Width	Δλ	IF=50mA		45		nm
Half Intensity Beam Angle	θ	IF=50mA		±3		deg
Switching Time	tr, tf	IF=50mA		40, 30		ns





Product No: MTE8560P-C



Unit: mm, Tolerance: ±0.2

The information contained herein is subject to change without notice.

2016-09-01